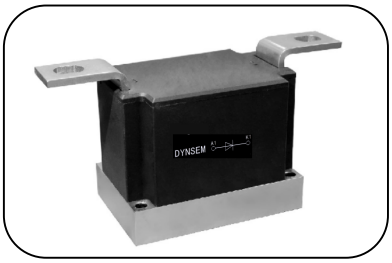
DYNSEM

DSKE1201
Diode modules



Features：

- **n** Isolated mounting base 3000V~
- **n** Pressure contact technology with Increased power cycling capability
- **n** Space and weight saving
- **n** UL Recognized

Typical Applications

- **n** Various rectifiers
- **n** DC supply for PWM inverter

V_{RRM}	Type
2000V	DSKE1201/20
2200V	DSKE1201/22
2500V	DSKE1201/25

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_j(°C)	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Single side cooled, T_C=100°C	150			1200	A
$I_{F(RMS)}$	RMS forward current		150			1884	A
I_{RRM}	Repetitive peak current	at V_{RRM}	150			50	mA
I_{FSM}	Surge forward current	10ms half sine wave , V_R=0.6V_{RRM}	150			30	kA
I^2t	I^2t for fusing coordination					4500	10^3A^2s
V_{FO}	Threshold voltage		150			0.70	V
r_F	Forward slope resistance					0.10	mΩ
V_{FM}	Peak forward voltage	I_{FM}=3000A	25			1.30	V
$R_{th(j-c)}$	Thermal resistance Junction to case	Single side cooled				0.042	°C/W
$R_{th(c-h)}$	Thermal resistance case to heatsink	Single side cooled				0.020	°C/W
V_{iso}	Isolation voltage	50Hz,R.M.S,t=1min,I_{iso}:1mA(max)		3000			V
F_m	Terminal connection torque(M12)			12.0		14.0	N·m
	Mounting torque(M6)			4.5		6.0	N·m
T_{vj}	Junction temperature			-40		150	°C
T_{stg}	Stored temperature			-40		125	°C
W_t	Weight				2700		g
Outline							

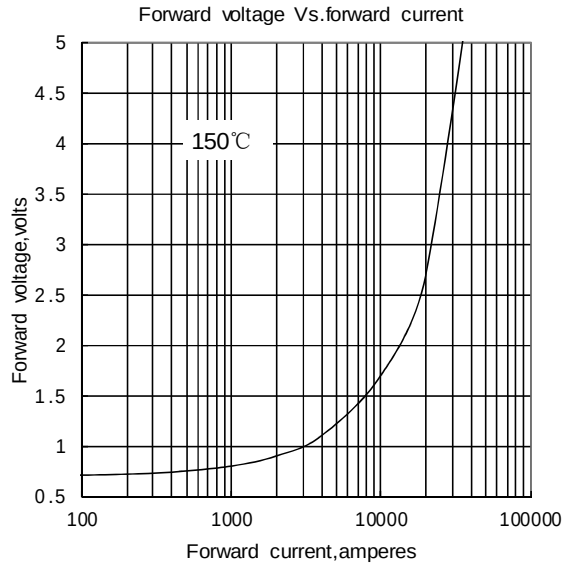


Fig.1

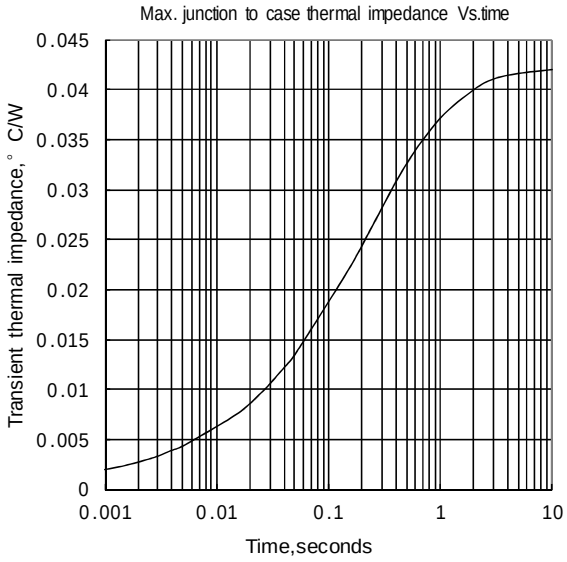


Fig.2

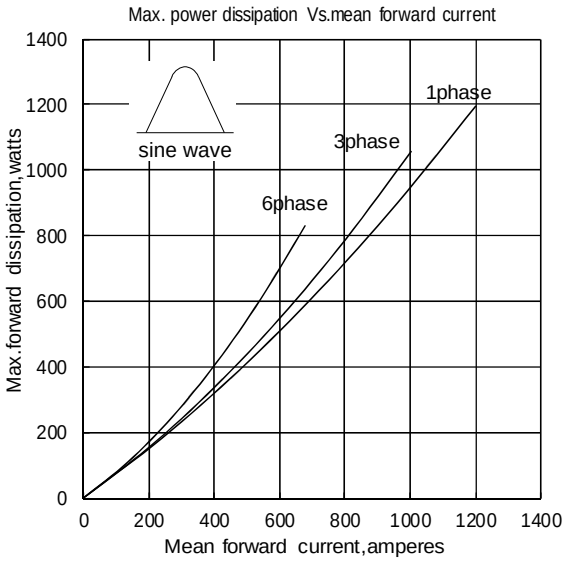


Fig.3

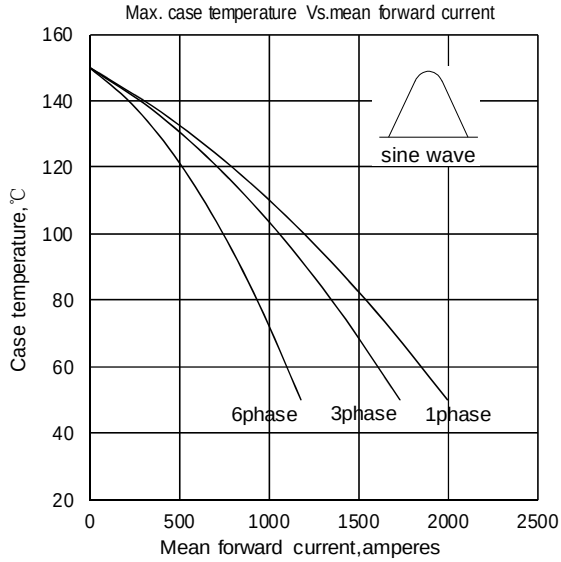
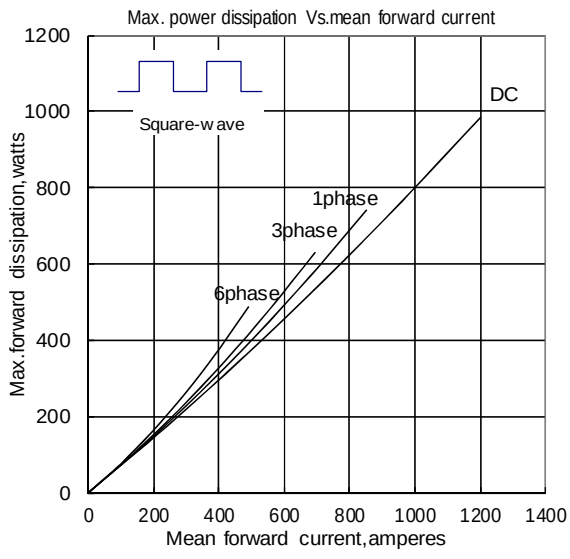


Fig.4



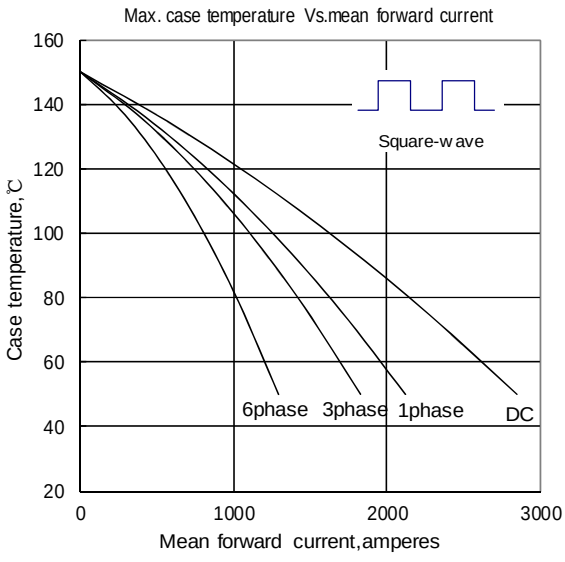


Fig.6

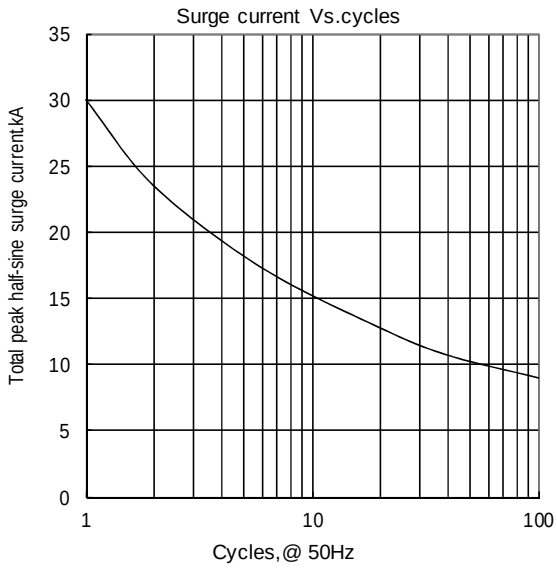


Fig.7

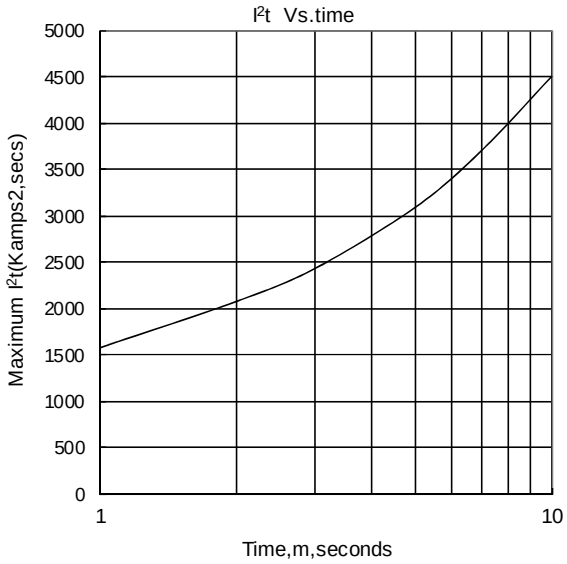
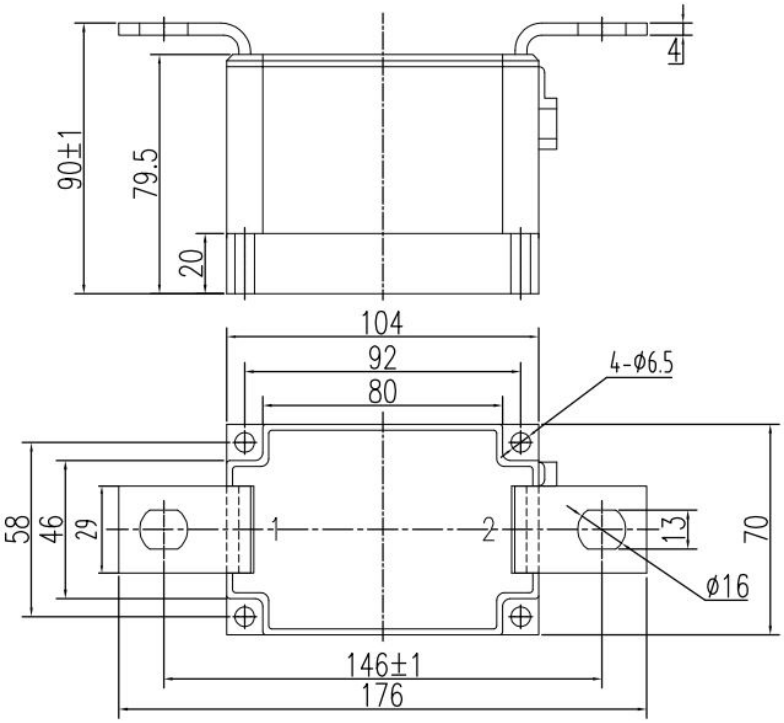
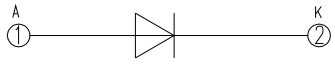


Fig.8

Outline:



DSKE



Unmarked dimensional tolerance：±0.5mm